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Normal-state charge dynamics in doped BaFe_2As_2 : Roles of doping and necessary ingredients for superconductivity

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In high-transition-temperature superconducting cuprates and iron arsenides, chemical doping plays an important role in inducing superconductivity. Whereas in the cuprate case, the dominant role of doping is to inject charge carriers, the role for the iron arsenides is complex owing to carrier multiplicity and the diversity of doping. Here, we present a comparative study of the in-plane resistivity and the optical spectrum of doped BaFe_2As_2 , which allows for separation of coherent (itinerant) and incoherent (highly dissipative) charge dynamics. The coherence of the system is controlled by doping, and the doping evolution of the charge dynamics exhibits a distinct difference between electron and hole doping. It is found in common with any type of doping that superconductivity with high transition temperature emerges when the normal-state charge dynamics maintains incoherence and when the resistivity associated with the coherent channel exhibits dominant temperature-linear dependence.

High-transition-temperature (high- T_c) superconductivity in iron arsenides is induced by various doping (chemical substitution) processes into metallic parent compounds showing an antiferromagnetic-orthorhombic (AFO) order. For a representative parent iron arsenide BaFe_2As_2 , the superconducting (SC) phase is attained by doping into all the three different lattice sites^{1–3}, and even by isovalent atomic substitution, e.g., P for As³ and Ru for Fe⁴. Notably, both electron and hole doping can generate superconductivity, in stark contrast to the case of high- T_c cuprates, in which only one type of carrier doping can induce superconductivity for one parent compound, and superconductivity is not achieved by substituting Ni or Zn for Cu in Mott insulating parent compounds.

The mechanism of various doping processes leading to the emergence of superconductivity is a matter of debate. Charge carriers appear to be supplied as revealed by the study of angle-resolved photoemission spectroscopy (ARPES), which demonstrates that the electron Fermi surface (FS) expands (the hole FS shrinks) for electron doping (e.g., Co substitution for Fe)^{5,6} and vice versa for hole doping (e.g., K substitution for Ba)⁷. However, how this contrasting doping evolution of the FS is reflected in charge transport has not been seriously studied. More fundamentally, the question of how a change in electron/hole density in already metallic parent compounds alters the electronic environment to favor superconductivity or whether the change in carrier density is really an important ingredient for superconductivity is nontrivial. In addition to the change in carrier density, a chemical-pressure effect also has a significant influence on the electronic structure^{8–10}. To gain a deeper understanding of the physics of doping in iron-based superconductors, it is of fundamental importance to extract universal natures such as the necessary ingredients for superconductivity among different doping processes. Because doping into BaFe_2As_2 covers the entire doping range from the AFO to the SC phase and further to the metallic non-SC end compounds, it is a suitable system for investigating the physical implications of doping.

Optical spectroscopy is a bulk-sensitive and energy-resolved probe and turns out to be a powerful tool to study charge dynamics and its evolution with doping in a multi-carrier system, particularly iron pnictides. The optical conductivity spectrum of iron arsenides is characterised by a small zero-energy peak, corresponding to a relatively coherent carrier dynamics, and a long tail extending to a high-energy region, indicative of the presence of an

incoherent charge dynamics with large spectral weight^{11–15}. Such a spectral feature is also seen in the spectrum of the high- T_c cuprates and characterises the normal-state charge dynamics in high- T_c superconductors. The combination of resistivity and optical conductivity makes it possible to separate the contribution of multiple carriers or to separate a coherent component from an incoherent one in charge dynamics by disentangling the carrier scattering rate from the carrier density. Indeed, the decomposition of the spectrum for Codoped BaFe_2As_2 explains the temperature and doping dependence of the charge dynamics well¹².

Here, we show how the magnitude and the temperature (T) dependence of the in-plane resistivity $\rho(T)$ evolve with doping (chemical substitution) into the three different sites in the parent compound BaFe_2As_2 : $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$, $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$, and $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ (abbreviated as Co-Ba122, P-Ba122, and K-Ba122, respectively). In the present study, we focus on the effect of doping in the high-temperature paramagnetic-tetragonal (PT) phase. The results of the doping evolution of resistivity and optical conductivity spectrum indicate that a dominant effect is to control coherence/incoherence in charge dynamics in different ways depending on the dopant sites/species. Superconductivity is found to emerge when the normal-state charge dynamics maintains incoherence. It is also found from the analysis of the T dependence of resistivity that, in the region of superconductivity showing fairly high T_c values, the normal-state resistivity is dominated by the T -linear scattering term.

Results

Doping evolution of in-plane resistivity. Figure 1 shows the doping evolution of $\rho(T)$ for the three systems, Co-, P-, and K-Ba122. The undoped parent compound BaFe_2As_2 , the quality of which is remarkably improved by annealing, shows very low residual resistivity ($< 10 \mu\Omega\text{cm}$) at low temperatures in the AFO phase, and the AFO-PT transition temperature T_s is 143 K, the highest among the temperatures so far reported^{16,17}. Nevertheless, the resistivity at 300 K is fairly high, $\sim 340 \mu\Omega\text{cm}$ and is comparable with that for unannealed crystals. The T dependence is weak in the PT phase above T_s , suggesting that the charge carriers are highly incoherent. The resistivity in the PT phase rapidly decreases with Co and P doping, in sharp contrast with that in the AFO phase, where the resistivity increases with doping, indicating that doping plays different roles in the two phases. In contrast, the change in magnitude is moderate in the case of K doping.

The evolution of $\rho(T)$ with Co doping is basically the same as that reported by Rullier-Albenque *et al.*¹⁸, except for a significantly lower resistivity in the AFO phase in the present result. With Co doping, the temperature dependence changes from T linear to T^2 in the

overdoped non-SC region. Note that a fairly large residual resistivity remains up to $x = 0.24$, indicating that a doped Co atom works as a relatively stronger scattering center. The substitution of P for As corresponds to chemically isovalent doping. The number of electrons and holes is expected to be balanced over the entire range of doping. Controversially, as in the case of Co-Ba122, the magnitude of the resistivity in the PT phase monotonically decreases with P doping, and the T dependence gradually changes from T -linear to T^2 , in agreement with the result obtained by Kasahara *et al.*³. A difference is that a doped P atom is a weaker scattering center as evidenced by a smaller residual-resistivity component. The doping evolution of $\rho(T)$ in K-Ba122 is in sharp contrast to the Co- and P-doping cases^{19,20}. Chemically, K doping corresponds to hole doping, but both the magnitude and T dependence of the resistivity only weakly change with doping. At low temperatures and at any doping level, the resistivity rapidly decreases with decreasing temperature, showing the T^2 dependence typical of a Fermi liquid, whereas it shows a clear tendency for saturation in the high-temperature PT phase. As far as the high- T region is concerned, even the end compound KFe_2As_2 with $T_c \sim 3.5$ K is not a good metal. Although a finite residual resistivity appears for the compounds showing the AFO order ($x \leq 0.23$), the magnitude of the residual resistivity for the K-doped compounds is considerably small compared with the Co- and P-doping cases, probably because a doped K atom is located farthest away from the Fe plane.

Doping evolution of optical conductivity spectrum. Figure 2(a) displays the optical conductivity spectrum of BaFe_2As_2 . The spectrum shows a small peak at $\omega = 0$ and a long tail merging into a broad peak in the higher-energy region. Using the Drude–Lorentz model, we decompose the spectrum as shown in Fig. 2(a). Because a single Drude component cannot reproduce the low-energy spectrum well, we decomposed the spectrum using two Drude components^{12,14,15,21–23}. Given that iron pnictides are multiband systems, the presence of multiple Drude components is a valid result. The black and orange lines indicate the experimental and fitting results, respectively. The low-energy conductivity is dominated by two Drude components with distinct characteristics: one is narrow with a small spectral weight (in blue) and the other is broad with a much larger spectral weight (in gray). A higher-energy component approximated by a Lorentzian function (in green) corresponds to an interband excitation.

The width of the broad Drude component (the scattering rate $1/\tau$) is $\sim 2000 \text{ cm}^{-1}$, corresponding to $\tau = 1.7 \times 10^{-14} \text{ s}$. From the band dispersions of BaFe_2As_2 obtained by ARPES measurements²⁴, it is seen that the Fermi velocity v_F of the band with a heavier effective mass is much less than $1.0 \times 10^6 \text{ cm/s}$. From this, the mean free path

Figure 1 | Doping evolution of temperature dependence of the in-plane resistivity for (a) Co-Ba122, (b) P-Ba122, and (c) K-Ba122.

Figure 2 | Decomposition of the optical conductivity spectrum at $T = 300$ K for (a) BaFe_2As_2 , (b–d) Co-Ba122, (e–h) P-Ba122, and (i) KFe_2As_2 .

$l (= v_F \tau)$ for the broad Drude component is estimated to be less than $1.7 \text{ \AA}$, which is significantly shorter than the shortest interatomic spacing ($2.4 \text{ \AA}$). On the other hand, for the narrow Drude component with a width of $\sim 200 \text{ cm}^{-1}$, we estimate the Fermi velocity to be $v_F \approx 3 \times 10^6 \text{ cm/s}$ and hence the mean free path to be $l \approx 50 \text{ \AA}$. It is considerably longer than the lattice parameter ($a \approx 4 \text{ \AA}$), which indicates relatively coherent charge dynamics. Hereafter, we call the narrow and broad Drude components the coherent and incoherent components (σ_D and σ_{in}), respectively. The incoherent component turned out to be nearly T independent as was previously pointed out^{12,21,23}, and the low-energy conductivity can be written as

$$\sigma(T, \omega) = \sigma_D(T, \omega) + \sigma_{in}(\omega). \quad (1)$$

The evolution of each component with x for Co-Ba122 is shown in Figs. 2(b)–2(d)¹². With Co doping, the weight of the narrow Drude component (coherent Drude weight) increases, whereas that of the broad Drude component shows no appreciable change. Figures 2(e)–2(h) show the evolution of the spectrum with P doping. The substitution of isovalent P for As supplies neither extra electrons nor holes. However, the coherent Drude weight remarkably increases with P doping without changing the total low-energy spectral weight below 6000 cm^{-1} ; the spectral weight is transferred to the coherent component from the higher-energy region¹⁰. As a result, the narrow

Drude component dominates in the low-energy spectrum of BaFe_2P_2 [Fig. 2(h)].

The decomposition of the spectrum of KFe_2As_2 [Fig. 2(i)] is nearly the same as that of BaFe_2As_2 , in which the fraction of the coherent Drude weight remains small, or even smaller, and hence the low-energy conductivity spectrum is also dominated by the incoherent component. In view of the spectrum presented in Ref. 25 for the K content $x = 0.4$, the highly incoherent spectrum seems to persist over the entire doping range of K-Ba122 without showing any appreciable spectral change.

Discussion

Here, we discuss the resistivity and optical conductivity results for the three doped BaFe_2As_2 systems in the context of the available results for the Hall coefficient and the FS observed by ARPES. In the high-temperature PT phase of BaFe_2As_2 , there are two electron FS pockets near the Brillouin zone boundary and three hole FS pockets around the zone center. Co doping makes the hole FS shrink and the electron FS expand^{5,6}. The Hall coefficient, indeed, decreases in magnitude with a negative sign as doping proceeds¹⁸. Hence, the increase in the coherent Drude weight with Co doping is associated predominantly with the increase in electron carriers supplied by the dopant Co atoms, and introduced electrons are not localised on the Co atom²⁶.

On the other hand, the hole FS expands (the electron FS shrinks) with K doping, and eventually the electron FS disappears in the highly doped region^{7,27}. However, the resistivity does not decrease appreciably with K doping, and the coherent Drude weight remains small over the entire doping range. These observations are in contrast to the electron-doped Co-Ba122 system. To reconcile these results with the doping evolution of the FS observed by ARPES, it is necessary to assume that quasiparticle states on a substantial part of the hole FS pockets remain incoherent in the hole-doped system.

The result for the isovalent P doping gives additional evidence for the electron–hole asymmetry. With P doping, the numbers of the electron and hole FS pockets do not change and thus the FS topology does not significantly change over the entire range of P content, although one of the hole FS pockets is more warped along the c -axis direction as x increases²⁴. Nevertheless, the P doping significantly increases the coherent Drude weight and decreases the resistivity, which transforms the bad metallic BaFe_2As_2 into a good metal as in the case of Co doping. The coherent Drude weight is affected by the carrier density and the effective mass (the influence of the effective mass will be discussed later). In view of the negative Hall coefficient, the magnitude of which decreases with increasing P content³, it follows that, as doping proceeds, the coherent region in the momentum space, which is originally restricted to a portion of the electron FS pockets, gradually expands within the electron FS pockets, while the states on the hole FS pockets remain incoherent. This agrees with the conclusion drawn from the contrasting evolution of coherence/incoherence for electron- and hole-doped BaFe_2As_2 . Earlier, it was reported that holes are subject to stronger scattering than electrons^{18,19,28}. The result of P-Ba122 is reminiscent of the hole-doped high- T_c cuprates, in which an increase in the hole doping level from the underdoped to the optimally doped region makes the coherent states extend from the nodal to the antinodal region on the FS above the pseudogap temperature.

In Fig. 3(a), we plot the weight of the narrow Drude component N_D as a function of the dopant concentration x for the three systems. N_D is calculated with

$$N_D = \frac{2m_0 V}{\pi e^2} \int_0^\infty \sigma_D(\omega) d\omega,$$

where m_0 and V are the free electron mass and the cell volume containing one Fe atom, respectively. N_D is proportional to the coherent carrier density n_D and inversely proportional to the carrier

Figure 3 | (a) Spectral weight of the narrow Drude component N_D as a function of element substitution content x . Co-Ba122, P-Ba122, and K-Ba122 are indicated as blue, orange, and red curves, respectively. Open symbols show the data from Refs. 10, 12, and 25. (b) $\omega = 0$ value of the broad Drude component as a function of x . Open and closed symbols show the values obtained from the decomposition of the optical conductivity spectrum (Fig. 2) and from the analysis of the temperature dependence of resistivity, respectively.

effective mass m^* : $N_D = \frac{m_0}{m^*} n_D$. Open symbols indicate the data compiled from Refs. 10, 12, and 25. Strikingly different evolutions of N_D are seen, despite the similar phase diagram for each system. For Co-Ba122, an initial increase in N_D with x is very steep. The N_D of P-Ba122 shows a superlinear increase with x , a gradual increase followed by a rapid increase for $x > 0.6$. The much faster increase in N_D with Co doping indicates that electron carriers are involved in the coherent charge dynamics. By contrast, the N_D for K-Ba122 weakly decreases with increasing x . Compared with the doping evolution of resistivity shown in Fig. 1, it is clear that the magnitude of resistivity follows N_D in the high- T region in each system. Note that, in the case of K doping, the resistivity only slightly decreases with x , but the hole density steadily increases with x , as evidenced by the increase in the volume of the hole FS observed by ARPES. The measurement of quantum oscillations for KFe_2As_2 revealed an enhancement in $m^{*29,30}$, indicating that the decrease in N_D is partly due to the increase in m^* . Probably, the coherent hole carrier density n_D would increase with a rate of increase slower than that of m^* . Unlike the K doping, a decrease in m^* with x (for $x > 0.3$) is reported for P doping by quantum oscillations³¹. m^* decreases by a factor of 2–3 from $x = 0.3$ to 1. In this respect, the increase in N_D for P-Ba122 may, in most part, be due to a decrease in m^* .

A bad metallic behavior in the iron arsenides manifests in the high- T region, where the magnitude of resistivity is fairly high, and the resistivity shows a tendency for saturation. This signals a dominant contribution of the broad (incoherent) Drude component at high temperatures in equation (1). σ_{in} is only weakly dependent on the temperature, which is found to reproduce the low-energy $\sigma(T, \omega)$ well^{12,23}. The resistivity saturation is understood in terms of conductivity in two channels at $\omega = 0$,

$$\rho^{-1}(T) = \sigma(T) = \sigma_D(T) + \sigma_{in}, \quad (2)$$

where σ_{in} is the $\omega = 0$ value of the incoherent conductivity term. For iron arsenides, σ_{in} is comparable with σ_D . The resistivity from the coherent component is expressed by the sum of the contributions from T -independent elastic and T -dependent inelastic scattering (ρ_0 and ρ_e , respectively); $\sigma_D^{-1}(T) = \rho_0 + \rho_e(T)$. With increasing temperature, σ_D decreases, and consequently the contribution of σ_{in} becomes dominant.

Equation (2) happens to be similar to a simple parallel resistor formula empirically describing the resistivity saturation, in which σ_{in} is replaced by ρ_{sat}^{-1} , ρ_{sat} being the maximum resistivity corresponding to the carrier mean free path equal to the lattice spacing³²: $\rho^{-1}(T) = \sigma_D(T) + \rho_{sat}^{-1}$. The present σ_{in} is not such a universal quantity but is dependent on the material and the doping level as shown in Fig. 3(b). This is distinct not only from the case of conventional resistivity saturating metals but also from the non-saturating resistivity of the known bad metals, many of which are in close proximity to a Mott insulating state, such as high- T_c cuprates^{33,34}. The non-saturating resistivity is thought to arise from a reduction in low-frequency conductivity with increasing temperature, the spectral weight of which is transferred to higher frequencies involving transitions to the upper Hubbard band^{34,35}. In iron arsenides, the presence of multiple carriers with distinct characteristics is responsible for the apparent resistivity saturation, and the highly incoherent hole carriers with a mean free path shorter than the lattice spacing¹⁴ are mainly responsible for the bad metallic behavior.

The result shown in Fig. 3(a) demonstrates that doping controls N_D in quite different ways depending on dopant sites and/or species. It is surprising that any of the different doping processes leads to the emergence of superconductivity. The critical doping level above which superconductivity appears more or less depends on the suppression rate of the AFO order, but it is an open question as to what conditions should be fulfilled for superconductivity to appear. On the other hand, the result indicates that the SC phase persists as long as N_D is sufficiently small [$N_D < 0.02$ – 0.03 , shaded region in Fig. 3(a)] and that the system cannot sustain superconductivity when N_D becomes larger or the charge dynamics becomes more coherent. N_D rapidly increases with Co doping, and soon reaches ~ 0.02 at $x \sim 0.10$. In the case of P doping, N_D increases slowly and exceeds 0.03 at approximately $x = 0.6$. This seems to corroborate the fact that the SC phase terminates at $x \sim 0.15$ and ~ 0.7 for Co and P doping, respectively. Unlike these two systems, the N_D of K-Ba122 maintains small values up to $x = 1$, consistent with the persistent superconductivity to KFe_2As_2 . The incoherent normal-state charge dynamics is therefore a prerequisite for superconductivity.

Finally, we analyse the T dependence of the resistivity in the PT phase predominantly arising from the coherent component and search for a correlation with superconductivity. Assuming the two parallel (inelastic) scattering channels, we adopt a dual-component analysis for the T -dependent part of resistivity, $\rho_e(T) = \alpha_1 T + \alpha_2 T^2$. The T^2 term is typical of a conventional Fermi liquid, and the T -linear term usually results from electron–boson interactions such as anti-ferromagnetic spin fluctuations. This dual-component analysis was applied to fit the resistivity of cuprates³⁶ and iron pnictides³⁷. However, this formula does not reproduce the trend for saturation observed for most iron arsenides at high temperatures. Therefore, we have to incorporate the incoherent channel σ_{in} explicitly and use the formula

$$1/\rho(T) = 1/(\rho_0 + \alpha_1 T + \alpha_2 T^2) + \sigma_{in}, \quad (3)$$

where ρ_0 represents the elastic scattering component adding to the inelastic scattering processes. σ_{in} can be estimated from the $\omega \rightarrow 0$ value of the broad (incoherent) Drude component in the present optical conductivity spectrum. For K-Ba122, larger values of σ_{in} are required to fit the resistivity curves than the experimentally extracted values. This might indicate that the decomposition of optical conductivity underestimates the contribution from the incoherent component, pointing towards the more incoherent charge dynamics inherent in K-Ba122 at high temperatures. Figure 4 shows the fitting results of the resistivity curves in the PT phase for the three systems under consideration. For undoped and underdoped compounds showing the AFO order, in-plane resistivity anisotropy is observed even in the PT phase above T_s , but the anisotropy is strongly suppressed by annealing^{16,38}, which guarantees the present

Figure 4 | Fitting of the temperature dependence of resistivity for Co-, P-, and K-Ba122 in the PT phase using the formula $1/\rho(T) = 1/(\rho_0 + \alpha_1 T + \alpha_2 T^2) + \sigma_{in}$.

fitting down to near T_s . Equation (3) with σ_{in} reproduces well the resistivity curves over a wide temperature and doping range.

Figures 5(a)–5(c) show the doping dependences of the coefficients of the T -linear and square terms multiplied by N_D , $\alpha_1 \cdot N_D$ and $\alpha_2 \cdot N_D$, respectively, for the three doping systems obtained using the best-fit parameters, α_1 and α_2 , to reproduce the resistivity curves (Fig. 4). For the compositions we did not measure the optical spectrum, N_D is estimated by assuming smooth variation with x , shown as the dashed curves in Fig. 3(a). In the framework of the present two-fluid and dual-channel analysis, $\alpha_1 \cdot N_D$ and $\alpha_2 \cdot N_D$ are more directly related to the scattering rate of the coherent carriers $1/\tau_D$ ($\sigma_D = N_D e^2 \tau_D / m_0$). In common with the three systems, $\alpha_1 \cdot N_D$ is largest near the AFO-SC phase boundary where T_c is highest, whereas it becomes vanishingly small in the overdoped regime where superconductivity disappears in Co- and P-Ba122. Superconductivity in K-Ba122 persists up to $x = 1$, but $\alpha_1 \cdot N_D$ remarkably decreases on going from $x = 0.69$ to 0.88. This probably corresponds to the disappearance of the electron FS pockets⁷ and/or the change in the SC gap function on FS from a nodeless³⁹ to a nodal one^{40,41}. Unlike $\alpha_1 \cdot N_D$, $\alpha_2 \cdot N_D$ remains finite over a wide range of doping regardless of the T_c value and does not show any noteworthy feature at the phase boundary. As shown in Fig. 3(a), the weight of the coherent Drude component N_D varies monotonically with x . Therefore, the non-monotonic change in $\alpha_1 \cdot N_D$ certainly arises from that of α_1 , the T -linear channel of the carrier scattering rate.

The predominance of the T -linear term implies stronger inelastic scattering of carriers, and the observed correlation between $\alpha_1 \cdot N_D$ and T_c strongly suggest that the scattering mechanism giving rise to the T -linear resistivity has an intimate connection with the SC-pair formation. Cooper *et al.* attempted to fit the temperature dependence

of the in-plane resistivity of highly doped $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ ($x > 0.15$) using a similar formula³⁶. They found that α_1 is largest at $x = 0.19$, which does not coincide with the composition showing the highest T_c , and decreases with an increase or a decrease in the doping level, whereas α_2 is only weakly dependent on the hole concentration down to $x = 0.19$. It should be noted that the T -linear resistivity in the hole-doped cuprates is different in nature. T -linearity in the cuprates persists up to very high temperatures, ~ 1000 K or even higher without showing resistivity saturation, and originates from highly incoherent quasiparticle states. The quasiparticle scattering rate ($1/\tau$) in the cuprates is strongly momentum (and frequency) dependent and is extremely high at momenta near the antinodes, $\hbar/\tau \sim 2\pi k_B T$, which is near the so-called Planckian dissipation limit^{36,42}. This is in contrast to the present iron pnictide case, in which the T -linear term arises from the coherent channel in parallel to the incoherent one, and the resistivity exhibits a tendency for saturation due to the nearly T -independent incoherent term. The width of the narrow Drude component is $\sim 200 \text{ cm}^{-1}$ at $T = 300$ K for every system near the doping level that produces the highest T_c value. This corresponds to $\hbar/\tau \sim k_B T$, which is by a factor of ~ 6 lower than that in $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$.

The T -linear resistivity is often invoked in relation to enhanced scattering from critical fluctuations near a quantum critical point (QCP). For P-Ba122, the presence of a magnetic QCP at $x \sim 0.3$ was suggested^{31,43}. The T -linear resistivity coefficient α_1 peaks at $x \sim 0.3$, and the effective mass m^* estimated from de Haas oscillations increases from the overdoped region towards $x \sim 0.3$. Unfortunately, it is not clear whether the QCP scenario is applicable to Co and K doping because there have been no reports of the evolution of m^* for Co- and K-Ba122. For every doped system, the SC phase is not confined to a region where α_1 (or $\alpha_1 \cdot N_D$) shows a peak and persists to $x = 1$ in the case of K-Ba122. Therefore, the present results support the scenario that superconductivity in the iron arsenides arises, irrespective of the presence or otherwise of a QCP, from strongly x -dependent coupling with some bosonic excitations, which is a source of the T -linear carrier scattering in the coherent component. For the incoherent component, the temperature dependence is very weak. This component experiences extremely strong scattering, which is presumably related to strong electronic correlations working orbital-selectively, already at low temperatures, and additional scattering channels, such as electron-boson scattering, would be no more visible at elevated temperatures.

The facts that α_1 and T_c attain large values near the AFO-SC phase boundary and that they steeply decrease farther away from the boundary suggest that the bosonic excitations originate from the fluctuations of the AFO order. As we discussed in the preceding study of the anomalous response of the AFO phase to dopant impurities^{38,44}, the AFO phase is a unique spin-charge-orbital complex.

Figure 5 | Doping evolution of the coefficients of the T -linear and T^2 components ($\alpha_1 \cdot N_D$ and $\alpha_2 \cdot N_D$, respectively) for (a) Co-Ba122, (b) P-Ba122, and (c) K-Ba122 determined from the fitting shown in Fig. 4. The $T = 0$ electronic phases are colour-coded: AFO in blue, SC in yellow, AFO-SC coexisting region in gradation, and non-SC metallic in white. Lower panels show the electronic phase diagrams for each system.

Hence, inelastic scattering from short-range dynamical spin-charge-orbital correlations is a candidate of the T -linear resistivity and hence pairing interactions.

Methods

Single crystals of Co-, P-, and K-doped BaFe_2As_2 were grown by the self-flux method^{12,45,46} and were post-annealed to improve the sample quality. Resistivity measurements were performed on the ab plane using the four-terminal method. Optical reflectivity was measured at $T = 300$ K with the incident light almost normal to the ab plane in the frequency range $50\text{--}40000\text{ cm}^{-1}$ using a Fourier transform infrared spectrometer (Bruker IFS113v) and a grating monochromator (JASCO CT-25C). The optical conductivity was derived from the Kramers–Kronig transformation of the reflectivity spectrum. The Hagen–Rubens or Drude–Lorentz formula was used for the low-energy extrapolation in order to smoothly connect to the spectrum in the measured region and to fit the measured resistivity value at $\omega = 0$.

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Author contributions

M.N. and T.T. conducted the optical spectroscopy measurements and analysed the data. M.N., K.K., T.S., C.H.L., H.F., Y.K. and A.I. synthesised the single crystals. M.N., S.I., Y.T., T.K. and T.I. carried out the resistivity measurements. H.E. and S.U. designed and coordinated the experiment. All authors contributed to and discussed the manuscript.

Additional information

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